

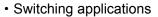
Isc N-Channel MOSFET Transistor

FCPF380N65FL1

FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation







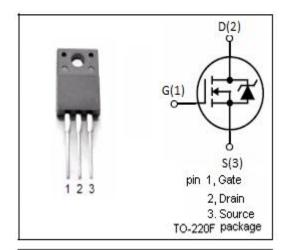
Power management

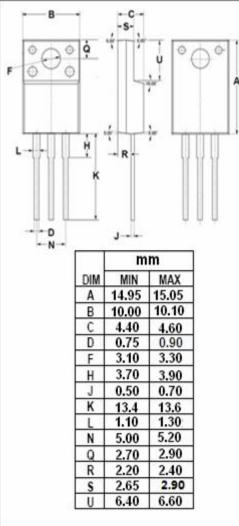
ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	650	V	
V _{GSS}	Gate-Source Voltage	±30	V	
I _D	Drain Current-ContinuousTc=25℃ 10.2 Tc=100℃ 6.4		А	
I _{DM}	Drain Current-Single Pulsed	30.6	А	
P _D	Total Dissipation @T _C =25°C 33		W	
Tj	Max. Operating Junction Temperature 150		${\mathbb C}$	
T _{stg}	Storage Temperature	-55~150	${\mathbb C}$	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	3.8	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C/W	







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	650			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =1mA	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =5.1A		0.32	0.38	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} =650V; V _{GS} = 0V;Tc=25℃ V _{DS} =520V; V _{GS} = 0V;Tc=125℃			10 100	μА
V _{SDF}	Diode forward voltage	I _{SD} =5.1A, V _{GS} = 0 V			1.2	V

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